

**TOSHIBA**

**2SA1162**

TOSHIBA TRANSISTOR SILICON PNP EPITAXIAL TYPE (PCT PROCESS)

# 2SA1162

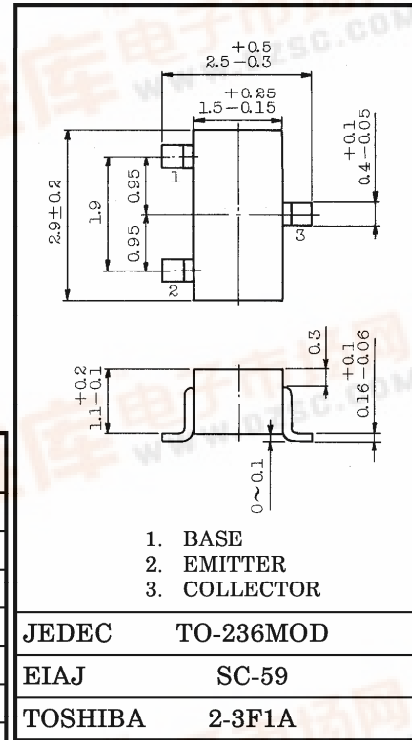
AUDIO FREQUENCY GENERAL PURPOSE AMPLIFIER APPLICATIONS.

Unit in mm

- High Voltage and High Current  
:  $V_{CEO} = -50V$ ,  $I_C = -150mA$  (Max.)
- Excellent  $h_{FE}$  Linearity  
:  $h_{FE}(I_C = -0.1mA) / h_{FE}(I_C = -2mA) = 0.95$  (Typ.)
- High  $h_{FE}$  :  $h_{FE} = 70 \sim 400$
- Low Noise :  $NF = 1dB$  (Typ.),  $10dB$  (Max.)
- Complementary to 2SC2712
- Small Package

MAXIMUM RATINGS ( $T_a = 25^\circ C$ )

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	-50	V
Collector-Emitter Voltage	$V_{CEO}$	-50	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Collector Current	$I_C$	-150	mA
Base Current	$I_B$	-30	mA
Collector Power Dissipation	$P_C$	150	mW
Junction Temperature	$T_j$	125	$^\circ C$
Storage Temperature Range	$T_{stg}$	-55~125	$^\circ C$



JEDEC	TO-236MOD
EIAJ	SC-59
TOSHIBA	2-3F1A

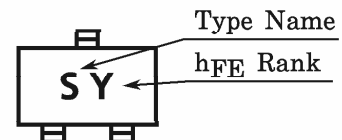
Weight : 0.012g

ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ C$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = -50V, I_E = 0$	—	—	-0.1	$\mu A$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = -5V, I_C = 0$	—	—	-0.1	$\mu A$
DC Current Gain	$h_{FE}$ (Note)	$V_{CE} = -6V, I_C = -2mA$	70	—	400	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -100mA, I_B = -10mA$	—	-0.1	-0.3	V
Transition Frequency	$f_T$	$V_{CE} = -10V, I_C = -1mA$	80	—	—	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = -10V, I_E = 0, f = 1MHz$	—	4	7	pF
Noise Figure	NF	$V_{CE} = -6V, I_C = 0.1mA, f = 1kHz, R_g = 10k\Omega$	—	1.0	10	dB

Note :  $h_{FE}$  Classification O(O): 70~140, Y(Y): 120~240, GR(G): 200~400 ( ) Marking Symbol

MARKING



961001FAA2

TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

